



浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO.,LTD.

产品规格书

Specifcation of products

产品名称：三相整流桥模块

产品型号：MDS35A-T11

浙江世菱半导体有限公司
ZHEJIANG SHILING SEMICONDUCTOR CO., LTD.

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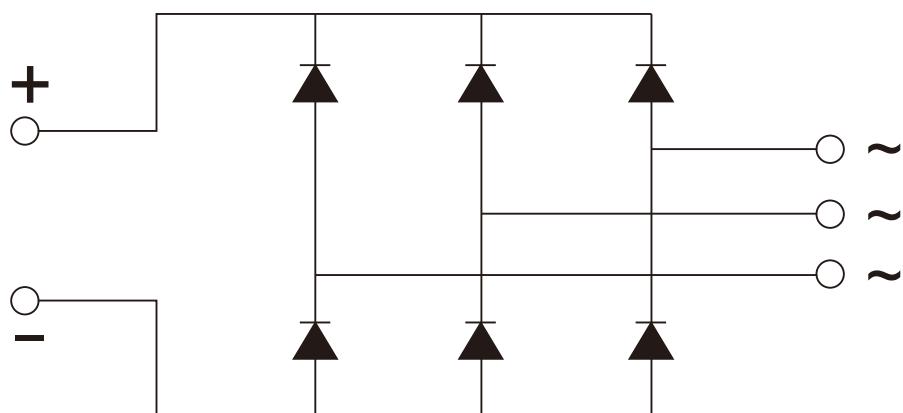
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拟制	审核	核准
林益龙	曹剑龙	宗瑞

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T_j (°C)	VALUE			UNIT
				Min	Type	Max	
I_o	DC output current	Three-phase full wave rectifying circuit, $T_c=100$ °C	150			35	A
V_{RRM}	Repetitive peak reverse voltage	V_{RRM} tp=10ms $V_{RsM}= V_{DRM}+V_{RRM}+200V$	150	800		2200	V
I_{RRM}	Repetitive peak current	at V_{RRM}	150			6	mA
I_{FSM}	Surge for ward current	10ms half sine wave	150			0.35	KA
I^2t	I^2T for fusing coordination	$V_R=0.6V_{RRM}$				0.81	A^2s*10^3
V_{FO}	Threshold voltage		150			0.80	V
r_F	Forward slop resistance					7.8	mΩ
V_{FM}	Peak for ward voltage	$I_{FM}=35A$	25			1.10	V
$R_{th(j-c)}$	Thermal resistance Junction to heatsink	Single side cooled				0.75	°C /W
V_{iso}	Isolation voltage	50Hz, RM. S, t=1min, I_{iso} : 1mA (max)		2500			V
F_m	Terminal connection torque						N.m
	Mounting torque(M5)					4.0	N.m
T_{Stg}	Stored temperature			-40		125	°C
W_t	Weight					107	g
Outline							

OUTLINE DR AWING & CIRCUIT DIAGRAM



Rating and Characteristic

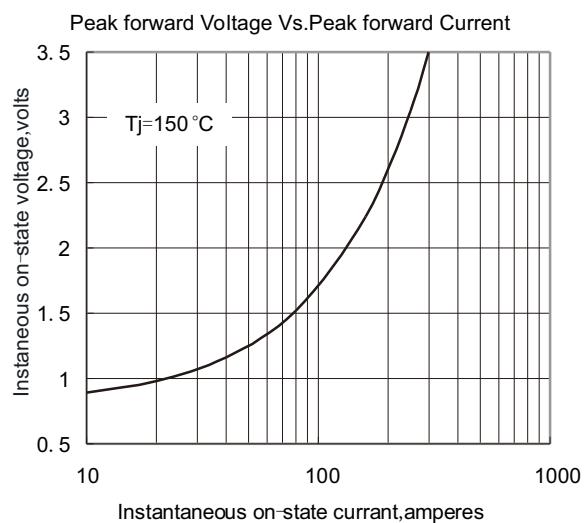


Fig. 1

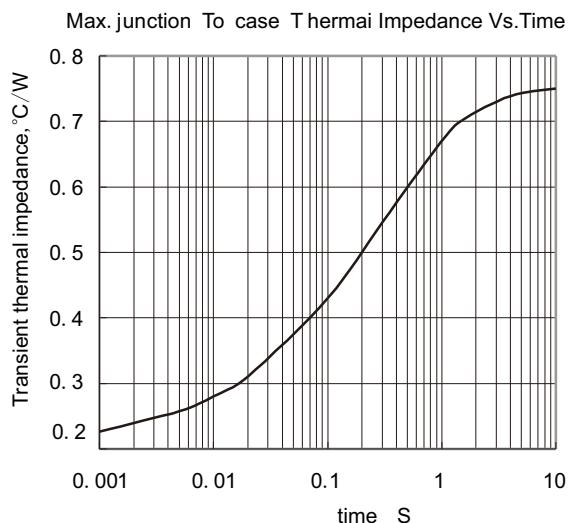


Fig. 2

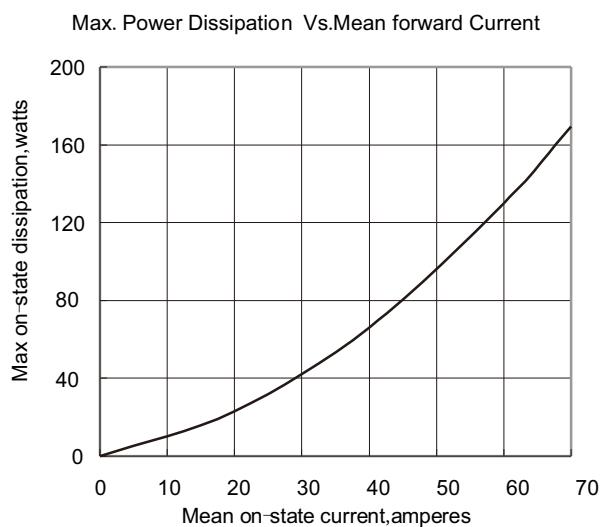


Fig. 3

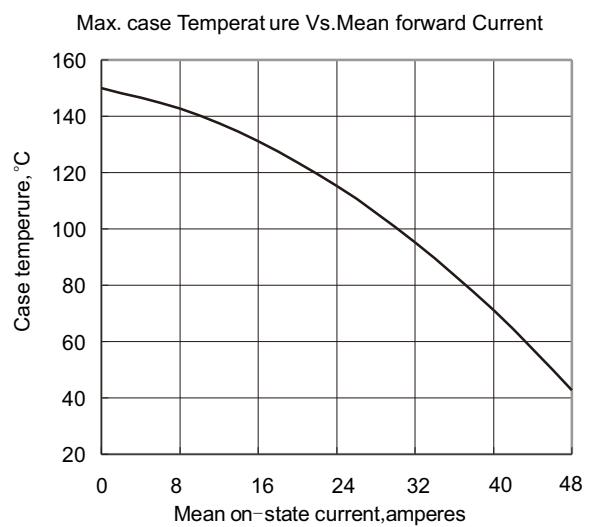


Fig. 4

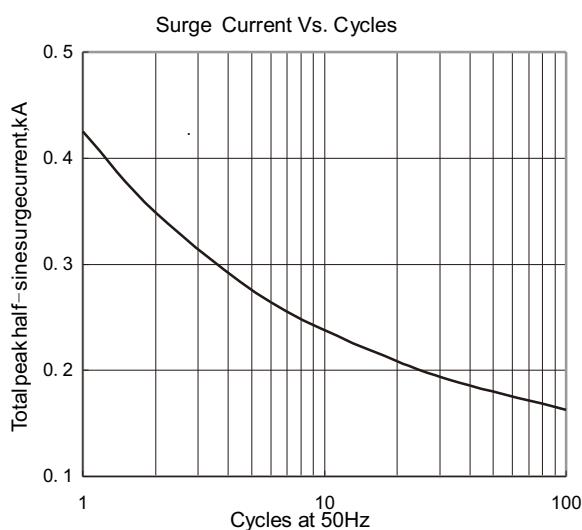


Fig. 5

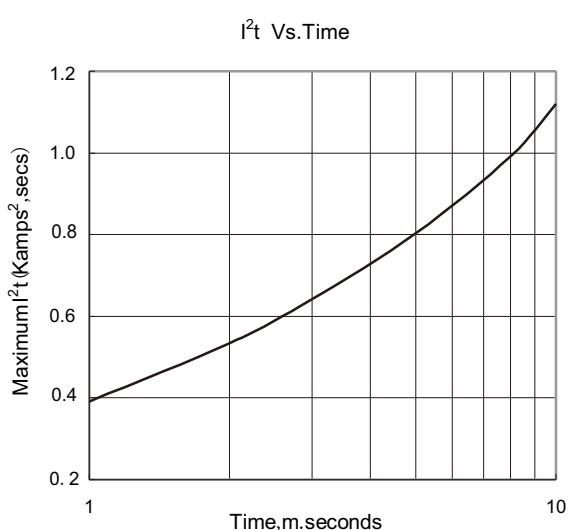


Fig. 6

Outside Dimension

